

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	117	(amorphous or porous) with (semiconductor adj layer) with (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:16
L2	102	(amorphous or porous) near10 (semiconductor adj layer) with (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:16
L3	43	(amorphous or porous) near10 (semiconductor adj layer) near10 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:16
L4	0	((amorphous or porous) adj region) near10 (semiconductor adj layer) near10 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:16
L5	0	((amorphous or porous) near region) near10 (semiconductor adj layer) near10 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:17
L6	0	((amorphous or porous) near2 region) near10 (semiconductor adj layer) near10 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:17
L7	43	((amorphous or porous)) near10 (semiconductor adj layer) near10 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:21
L8	2	((amorphous or porous)) near10 between near5 (semiconductor adj layer) near2 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:22
L9	3	((amorphous or porous)) near10 between near5 (semiconductor adj layer) near5 (passivation adj (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:22